High-Current Complementary Silicon Power Transistors

These packages are designed for use in high-power amplifier and switching circuit applications.

Features

- High Current Capability I_C Continuous = 50 Amperes
- DC Current Gain $h_{FE} = 15-60$ @ $I_C = 25$ Adc
- Low Collector-Emitter Saturation Voltage - $V_{CE(sat)} = 1.0 \text{ Vdc} (Max) @ I_C = 25 \text{ Adc}$
- Pb-Free Packages are Available*

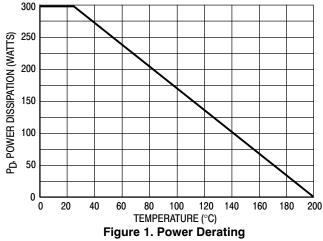
MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	80	Vdc
Collector-Base Voltage	V _{CB}	80	Vdc
Emitter-Base Voltage	V _{EB}	5.0	Vdc
Collector Current – Continuous	Ι _C	50	Adc
Base Current	Ι _Β	15	Adc
Total Power Dissipation @ $T_C = 25^{\circ}C$ Derate above $25^{\circ}C$	PD	300 1.715	mW mW/°C
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to +200	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	θJC	0.584	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Indicates JEDEC Registered Data.

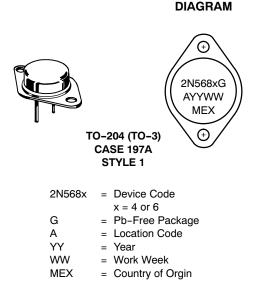


ON Semiconductor®

http://onsemi.com

50 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 60-80 VOLTS, 300 WATTS

MARKING



ORDERING INFORMATION

Device	Package	Shipping
2N5684G	TO-3 (Pb-Free)	100 Units/Tray
2N5686	TO-3	100 Units/Tray
2N5686G	TO-3 (Pb-Free)	100 Units/Tray

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Safe Area Curves are indicated by Figure 5. All limits are applicable and must be observed.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted) (Note 2)

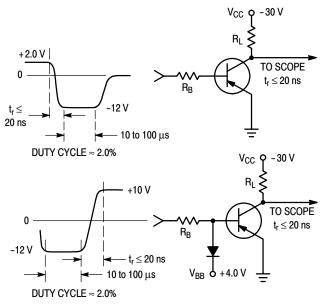
Charact	teristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS					•
Collector-Emitter Sustaining Voltage (Note 3	3) $(I_{\rm C} = 0.2 {\rm Adc}, I_{\rm B} = 0)$	V _{CEO(sus)}	80	-	Vdc
Collector Cutoff Current	$(V_{CE} = 40 \text{ Vdc}, I_B = 0)$	I _{CEO}	-	1.0	mAdc
Collector Cutoff Current (V _{CE} =	(V _{CE} = 80 Vdc, V _{EB(off)} = 1.5 Vdc) 80 Vdc, V _{EB(off)} = 1.5 Vdc, T _C = 150°C)	I _{CEX}	-	2.0 10	mAdc
Collector Cutoff Current	$(V_{CB} = 80 \text{ Vdc}, I_E = 0)$	I _{CBO}	-	2.0	mAdc
Emitter Cutoff Current	$(V_{BE} = 5.0 \text{ Vdc}, I_{C} = 0)$	I _{EBO}	-	5.0	mAdc
ON CHARACTERISTICS					
DC Current Gain (Note 3)	$(I_{C} = 25 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc})$ $(I_{C} = 50 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc})$	h _{FE}	15 5.0	60 -	-
Collector-Emitter Saturation Voltage (Note 3	3) (I _C = 25 Adc, I _B = 2.5 Adc) (I _C = 50 Adc, I _B = 10 Adc)	V _{CE(sat)}	-	1.0 5.0	Vdc
Base-Emitter Saturation Voltage (Note 2)	$(I_{C} = 25 \text{ Adc}, I_{B} = 2.5 \text{ Adc})$	V _{BE(sat)}	-	2.0	Vdc
Base-Emitter On Voltage (Note 2)	$(I_{C} = 25 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc})$	V _{BE(on)}	-	2.0	Vdc
DYNAMIC CHARACTERISTICS					
Current-Gain - Bandwidth Product (I	_C = 5.0 Adc, V _{CE} = 10 Vdc, f = 1.0 MHz)	f _T	2.0	-	MHz
Output Capacitance (V_{CB} = 10 Vdc, I _E = 0, f = 0.1 MHz)	2N5684 2N5686	C _{ob}	- -	2000 1200	pF

 $(I_C = 10 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}, f = 1.0 \text{ kHz})$

2. Indicates JEDEC Registered Data.

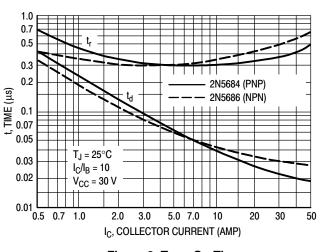
Small-Signal Current Gain

3. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.



FOR CURVES OF FIGURES 3 & 6, ${\sf R}_{\sf B}$ & ${\sf R}_{\sf L}$ are varied. Input levels are approximately as shown. For NPN CIRCUITS, reverse all polarities.





h_{fe}

15

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Figure 3. Turn-On Time

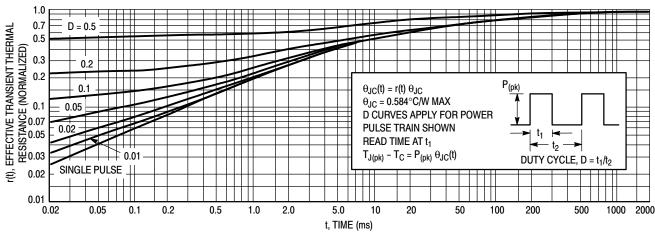
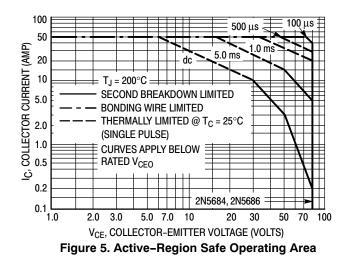


Figure 4. Thermal Response



There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 200^{\circ}$ C; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 200^{\circ}$ C. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

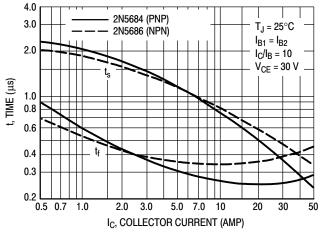
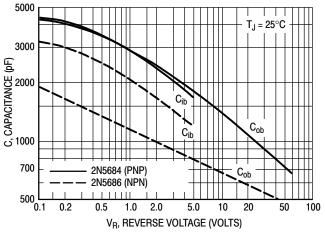
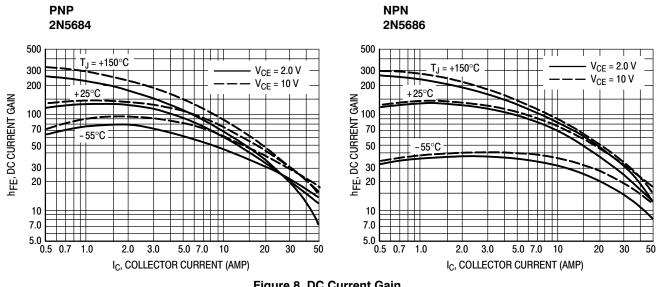


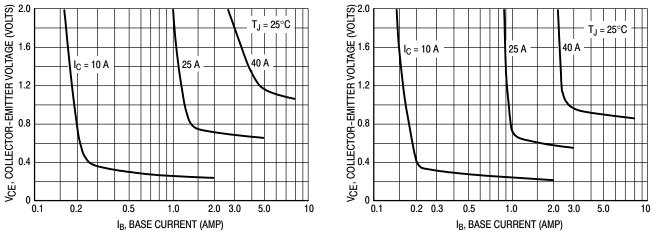
Figure 6. Turn-Off Time

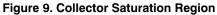


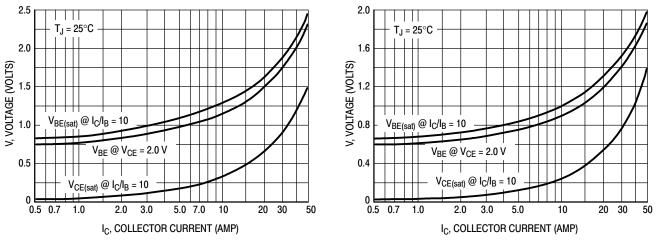


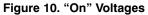




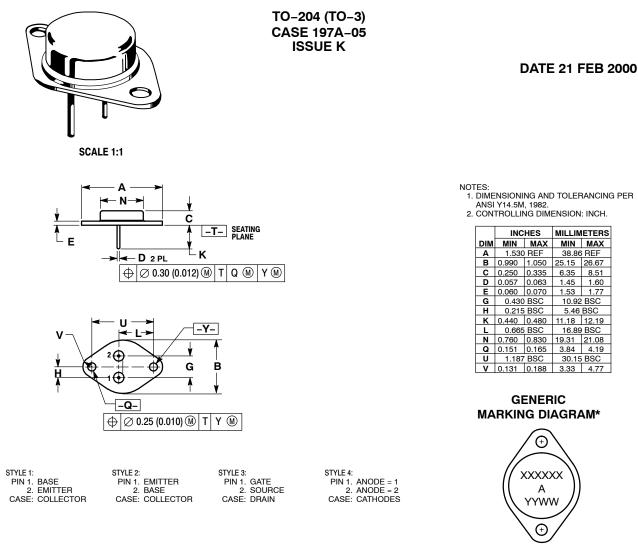












XXXXX = Specific Device Code

A = Assembly Locationa

YY = Year

WW = Work Week

*This information is generic. Please refer to device data sheet for actual part marking.

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